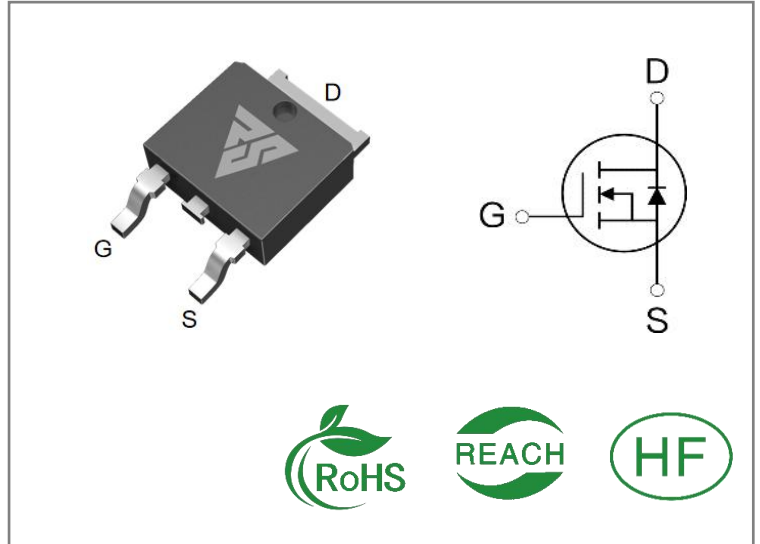


ID	R _{Ds(ON)} (Typ)	VDSS
5A	1.25Ω	500V


Applications:

- Switch Mode Power Supply(SMPS)
- Adapter & Charger
- AC-DC Switching Power Supply

Features:

- Fast switching speed
- 100% avalanche tested
- Improved dv/dt capability

Ordering Information

Part Number	Package	Marking	Packing	Qty.
RS5N50D	T0-252	RS5N50D	Tape&reel	2500 PCS

Absolute Maximun Ratings Tc= 25℃ unless otherwise specified

Symbol	Parameter	RS5N50D	Units
VDSS	Drain-to-Source Voltage	500	V
ID	Continuous Drain Current TC=25℃	5	A
	Continuous Drain Current TC=100℃	3	
IDM	Pulsed Drain Current	20	
PD	Power Dissipation	52	W
VGS	Gate- to- Source Voltage	±30	V
EAS	Single Pulse Avalanche Engergy L = 10mH, VDD = 50V, RG = 25Ω	200	mJ
TL TPKG	Maximum Temperature for Soldering	300 260	℃
	Leads at 0.063in(1.6mm)from Case for 10 seconds Package Body for 10 seconds		
TJ and TSTG	Operating Junction and Storage Temperature Range	-55 to 150	

* Drain Current Limited by Maximum Junction Temperature

Caution: Stresses greater than those listed in the“ Absolute Maximum Ratings” Table may cause permanent damage to the device.

Thermal Resistance

Symbol	Parameter	RS5N50D	Units	Test Conditions
R θ JC	Junction-to-Case	2.6	°C / W	Drain lead soldered to water cooled heatsink, PD adjusted for a peak junction temperature of + 1 5 0 °C
R θ JA	Junction-to-Ambient	62		1 cubic foot chamber, free air.

OFF Characteristics T_J= 25°C unless otherwise specified

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
BVDSS	Drain- to- source Breakdown Voltage	500	--	--	V	V _{GS} =0V, I _D =250μA
IDSS	Drain- to- Source Leakage Current	--	--	1	μA	V _{DS} =500V, V _{GS} =0V
IGSS	Gate- to- Source Forward Leakage	--	--	100	nA	V _{GS} =30V , V _{DS} =0V
	Gate- to- Source Reverse Leakage	--	--	-100		V _{GS} =-30V , V _{DS} =0V

ON Characteristics T_J=25°C unless otherwise specified

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
R _{DS(on)}	Static Drain- to- Source On-Resistance(Note*2)	--	1.25	1.45	Ω	V _{GS} =10V, I _D =2.5A
V _{GS(TH)}	Gate Threshold Voltage	2	3	4	V	V _{GS} =V _{DS} , I _D =250μA

Resistive Switching Characteristics Essentially independent of operating temperature

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
t _{d(ON)}	Turn- on Delay Time	--	24	--	nS	V _{DS} =250V I _D =5A R _G =10Ω
t _{rise}	Rise Time	--	18	--		
t _{d(OFF)}	Turn- OFF Delay Time	--	52	--		
t _{fall}	Fall Time	--	31	--		

Dynamic Characteristics Essentially independent of operating temperature

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
Ciss	Input Capacitance	--	478	--	pF	VGS=0V VDS=25V f=1.0MHz
Coss	Output Capacitance	--	55	--		
Crss	Reverse Transfer Capacitance	--	6.7	--		
Qg	Total Gate Charge	--	16	--	nC	VDS=400V ID=5A VGS=10V
Qgs	Gate- to- Source Charge	--	3.5	--		
Qgd	Gate-to-Drain(" Miller") Charge	--	5.5	--		

Source- Drain Diode Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
IS	Continuous Source Current	--	--	5	A	Integral pn- diode in MOSFET
ISM	Maximum Pulsed Current	--	--	20	A	
VSD	Diode Forward Voltage	--	--	1.4	V	IS=5A,VGS=0V
trr	Reverse Recovery Time	--	408	--	nS	VR=400V IF=5A,di/dt=100 A/μs
Qrr	Reverse Recovery Charge	--	1.5	--	μC	

Notes:

- * 1. Repetitive rating, pulse width limited by maximum junction temperature.
- * 2. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty Cycle $\leq 1\%$

Typical Feature Curve

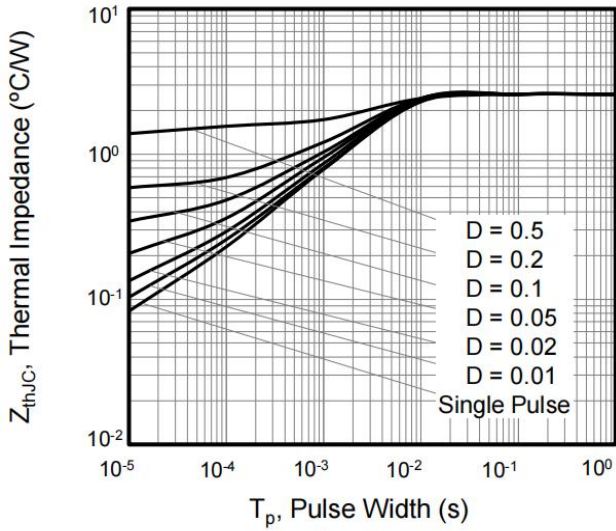


Figure 1. Transient Thermal Impedance

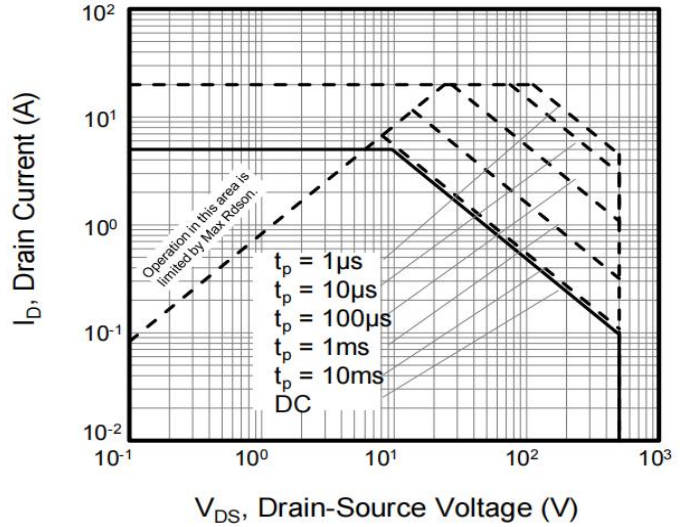


Figure 2. Safe Operation Area

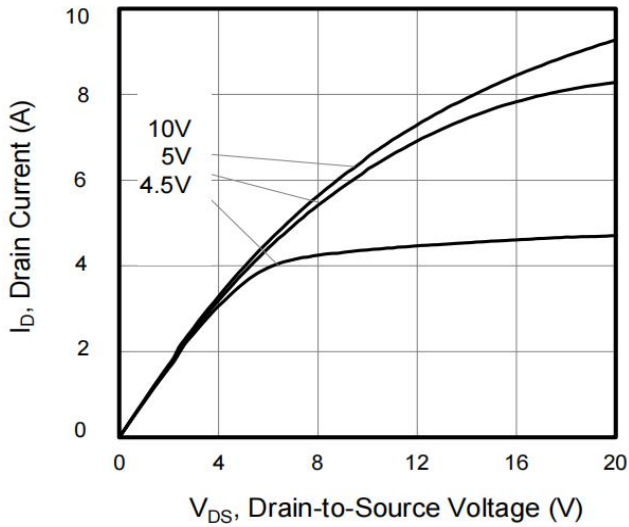


Figure 3. Output Characteristics

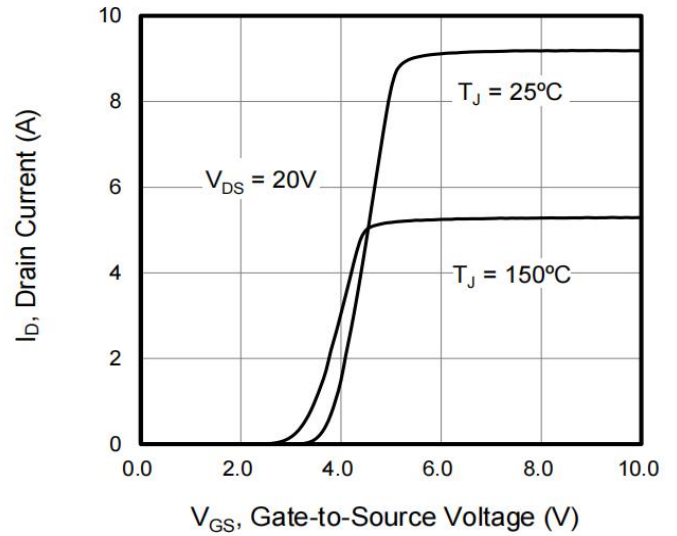


Figure 4. Transfer Characteristics

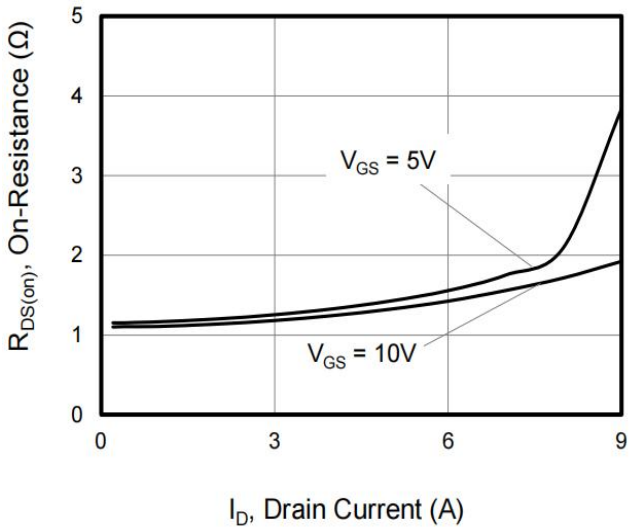


Figure 5. On-Resistance vs Drain Current

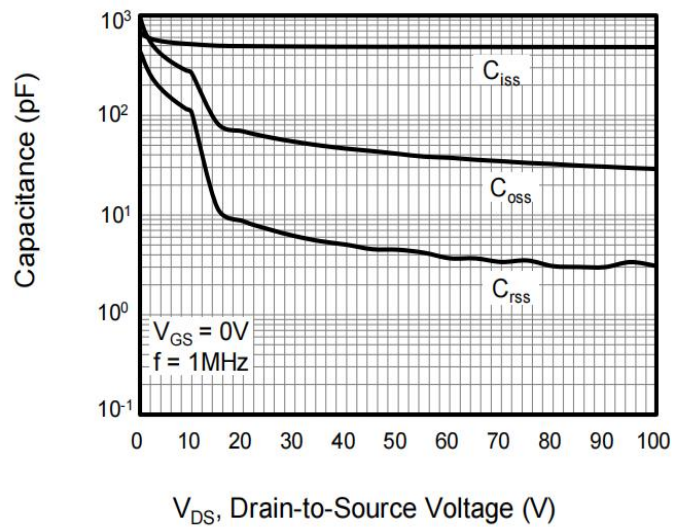


Figure 6. Capacitance

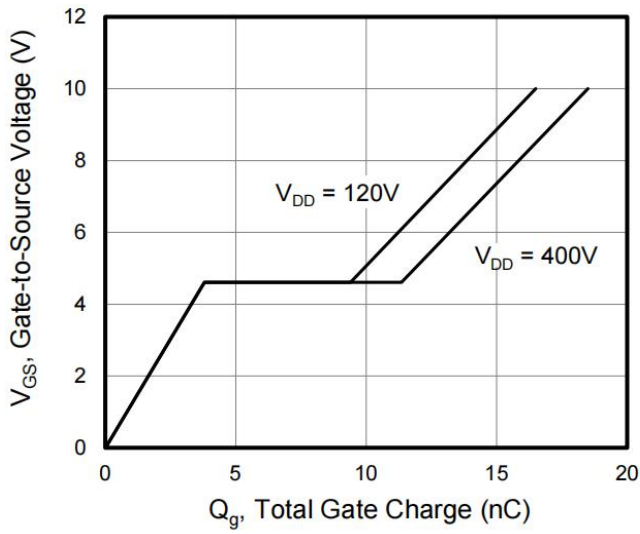


Figure 7. Gate Charge

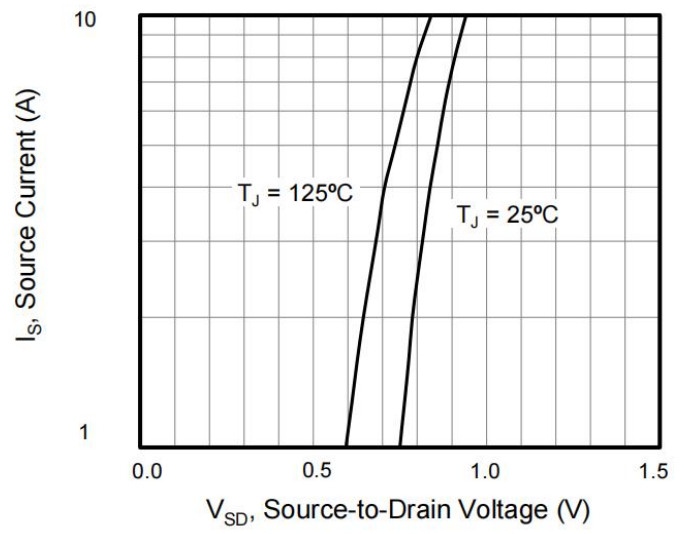


Figure 8. Body Diode Forward Voltage

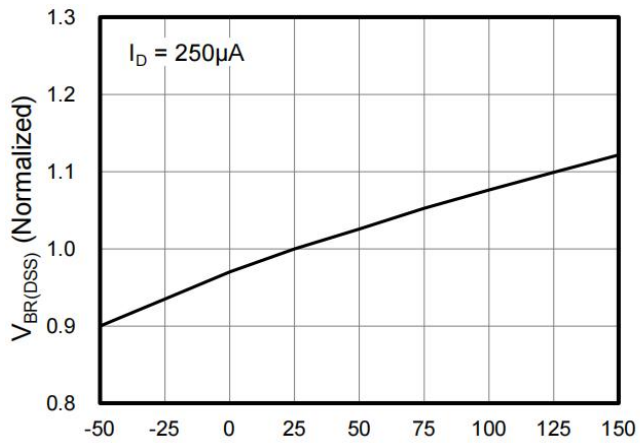


Figure 9. Breakdown Voltage vs Junction Temperature

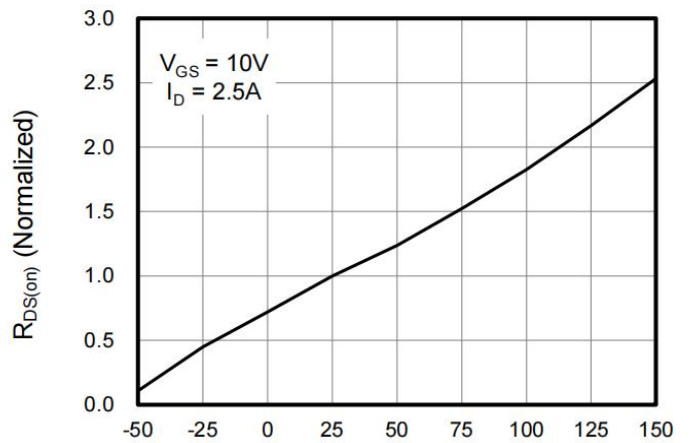


Figure 10. On-Resistance vs Temperature

Test Circuits and Waveforms

Figure A: Gate Charge Test Circuit and Waveform

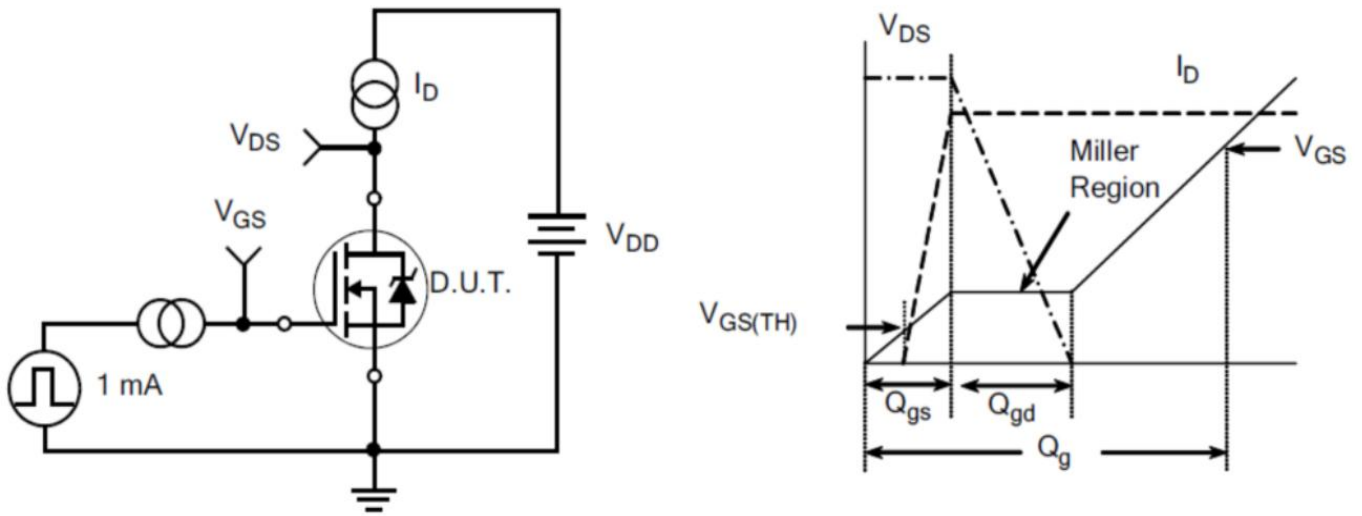


Figure B: Resistive Switching Test Circuit and Waveform

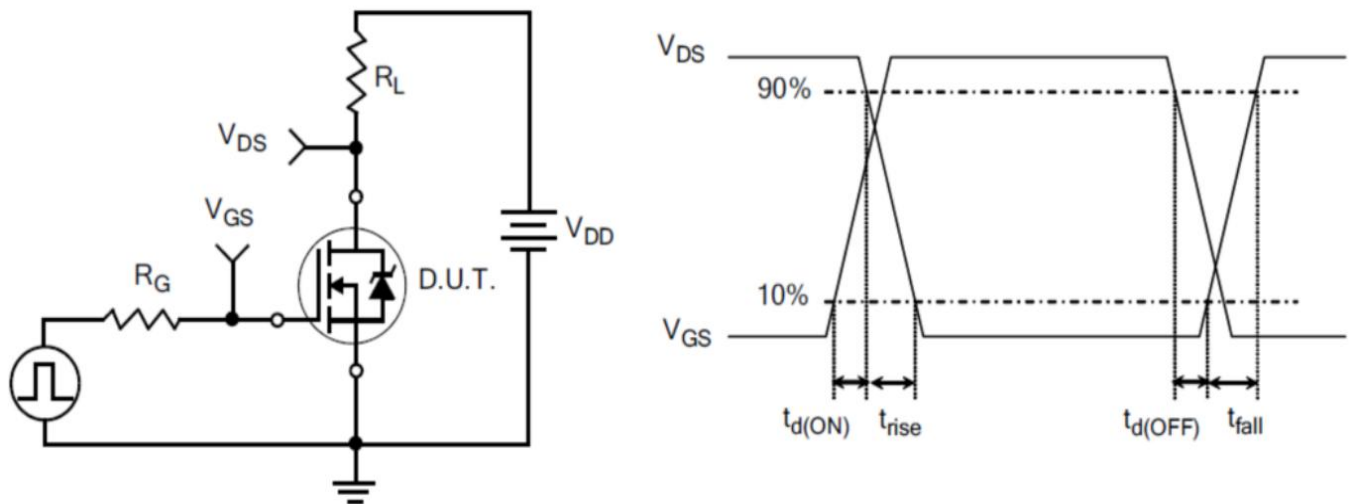
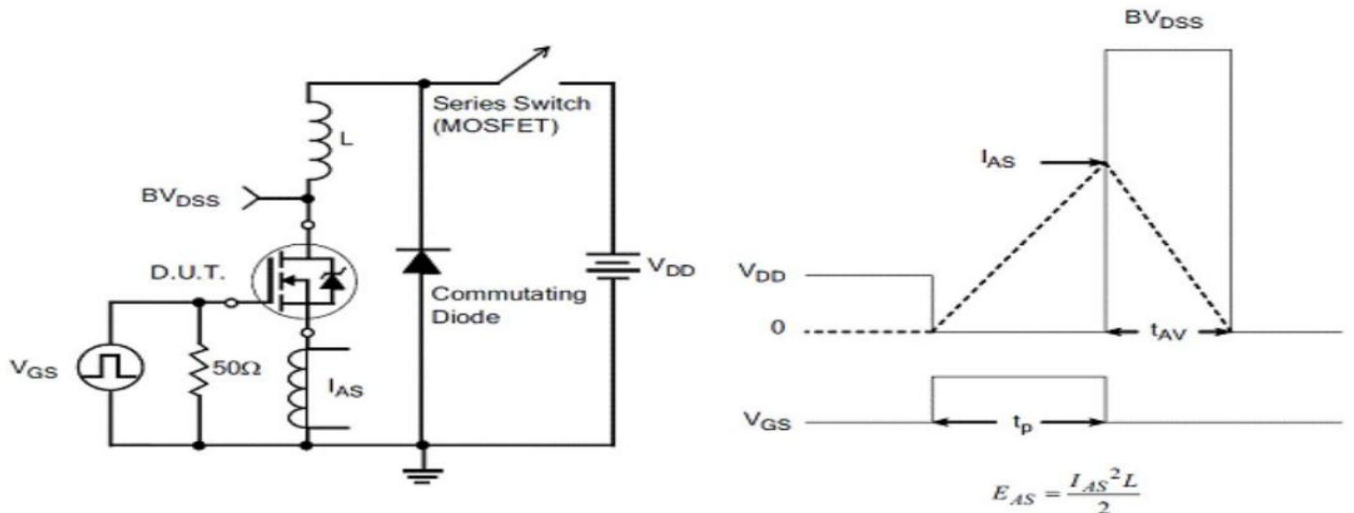
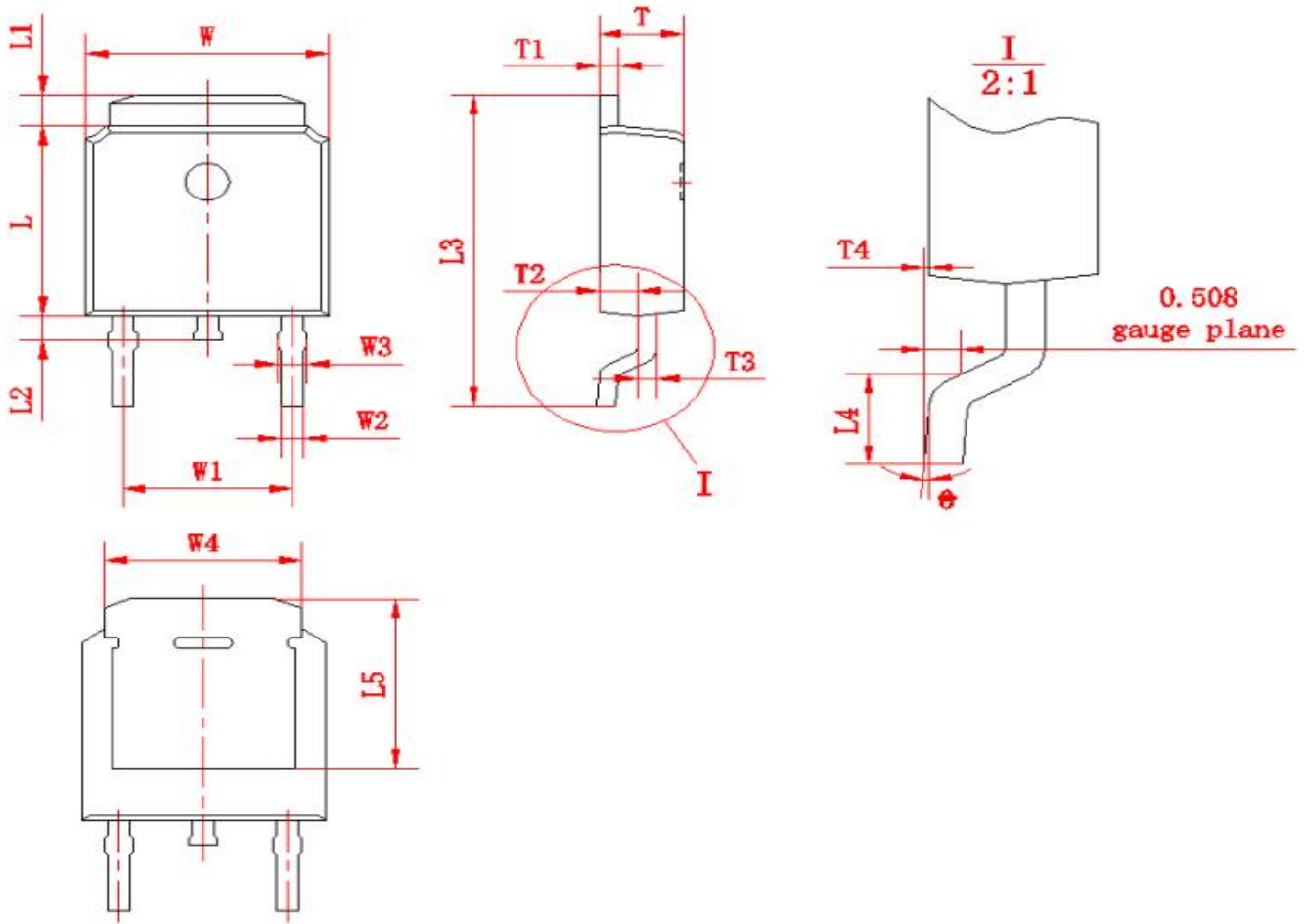


Figure C: Unclamped Inductive Switching Test Circuit and Waveform



Package outline drawing(TO-252 Unit: mm)



符号	尺寸		符号	尺寸		符号	尺寸	
	Min	Max		Min	Max		Min	Max
W	6.50	6.70	L1	0.80	1.20	T1	0.48	0.58
W1	(4.572)		L2	0.60	1.00	T2	0.95	1.15
W2	0.6	0.8	L3	9.70	10.30	T3	0.48	0.58
W3	0.68	0.88	L4	1.30	1.70	T4	0.00	0.12
W4	(5.3)		L5	(5.20)		0	0	8
L	6.00	6.20	T	2.20	2.40			

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